

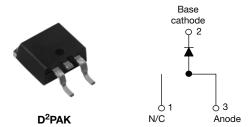


Vishay High Power Products

RoHS COMPLIANT HALOGEN

FREE

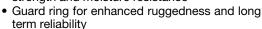
Schottky Rectifier, 10 A



PRODUCT SUMMARY					
I _{F(AV)}	10 A				
V _R	35 V/45 V				
I _{RM}	15 mA at 125 °C				

FEATURES

- 150 °C T_J operation
- TO-220 and D²PAK packages
- Low forward voltage drop
- High frequency operation
- High purity, high temperature open, encapsulation for enhanced mechanical resistance.



- · Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Halogen-free according to IEC 61249-2-21 definition
- Compliant to RoHS directive 2002/95/EC
- AEC-Q101 qualified

DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	10	۸			
I _{FRM}	T _C = 135 °C	20	Α			
V _{RRM}		35/45	V			
I _{FSM}	t _p = 5 μs sine	1060	А			
V _F	10 Apk, T _J = 125 °C	0.57	V			
T _J	Range	- 65 to 150	°C			

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-MBRB1035PbF VS-MBRB1045PbF UNITS						
Maximum DC reverse voltage	V_{R}	35	45	V		
Maximum working peak reverse voltage	V_{RWM}	33	45	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CON	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	T _C = 135 °C, rated V _R		10		
Peak repetitive forward current	I _{FRM}	Rated V _R , square wave, 20 k	kHz, T _C = 135 °C	20		
Non-repetitive surge current	I _{ESM}	Following any rated load condition and with rated V _{RRM} applied		1060	А	
		Surge applied at rated load conditions halfwave, single phase, 60 Hz		150		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 4 mH		8	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		2	А	

VS-MBRB1035PbF, VS-MBRB1045PbF

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
		20 A	T _J = 25 °C	0.84		
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	T 405.00	0.57	V	
		20 A	- T _J = 125 °C	0.72		
Maximum instantaneous reverse	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.1	mA	
current	'RM '''	T _J = 125 °C	hated DC voltage	15		
Threshold voltage	V _{F(TO)}	T - T movimum		0.354	V	
Forward slope resistance	r _t	ij = ijillaxilliulli	$T_J = T_J$ maximum		mΩ	
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		600	pF	
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs		

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction tempera	ture range	TJ	TJ		°C	
Maximum storage temperat	ure range	T _{Stg}		- 65 to 175	°C	
Maximum thermal resistance junction to case	e,	R _{thJC}	DC operation	2.0	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (Only for TO-220)	0.50	C/VV	
Approximate weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf · cm	
Mounting torque	maximum			12 (10)	(lbf \cdot in)	
Marking device			Occupation P ² PAIX		31035	
			Case style D ² PAK	MBRE	MBRB1045	



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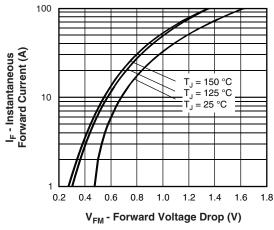


Fig. 1 - Maximum Forward Voltage Drop Characteristics

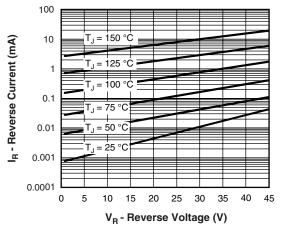


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

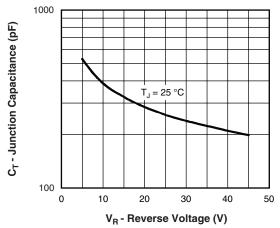


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

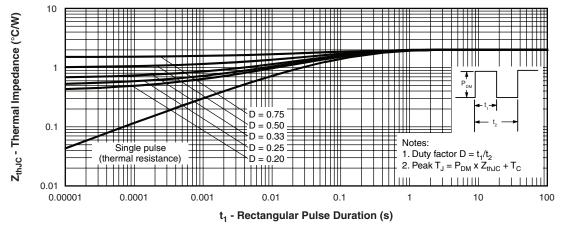


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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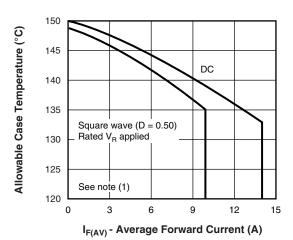


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

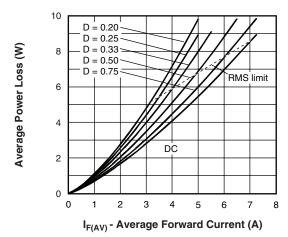


Fig. 6 - Forward Power Loss Characteristics

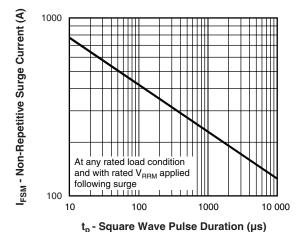


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = Rated V_R$

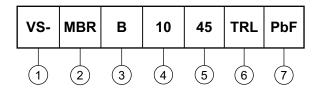


VS-MBRB1035PbF, VS-MBRB1045PbF

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ORDERING INFORMATION TABLE

Device code



- 1 HPP product suffix
- 2 Essential part number
- 3 B = Surface mount
- 4 Current rating (10 = 10 A)
 - Voltage ratings 35 = 35 V 45 = 45 V
- 6 • None = Tube (50 pieces)
 - TRL = Tape and reel (left oriented)
 - TRR = Tape and reel (right oriented)
- 7 PbF = Lead (Pb)-free

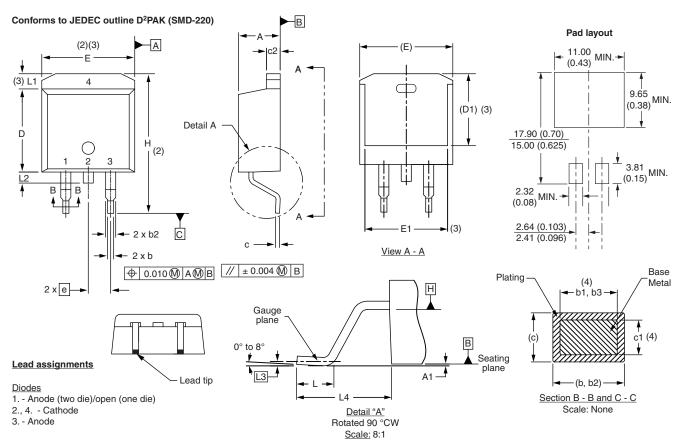
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95046</u>					
Part marking information	www.vishay.com/doc?95054				
Packaging information	www.vishay.com/doc?95032				
SPICE model	www.vishay.com/doc?95293				



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	IILLIMETERS INCHES		NOTES	
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	1	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- $^{(1)}$ Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC outline TO-263AB



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Vishay

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Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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Revision: 02-Oct-12 Document Number: 91000